



Crystal Growth of CdTe and (Cd,Zn)Te

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1. Introduction - material importance
2. II-VI material parameters and melt “structure”
3. Growth methods (CZ, BR, VGF, THM, PVD)
4. Point defects - intrinsic and high-resistivity doping
5. Dislocation dynamics - cell structuring
6. Te inclusions/precipitates via non-stoichiometry
7. Stacking faults and twinning
8. Summary and conclusions